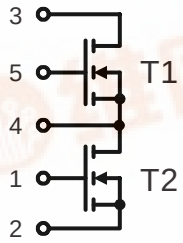
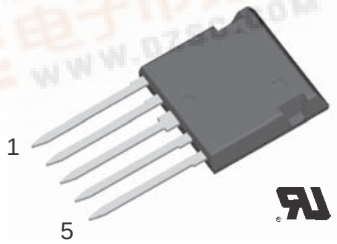
Trench Power MOSFET

-Phaseleg Topology-
in ISOPLUS i4-PAC™
with DAB Base

I_{D25} = 200 A
V_{DSS} = 75 V
R_{DSon} = 3.5 mΩ





MOSFET T1/T2

Symbol	Conditions	Maximum Ratings	
V_{DSS}	T_{VJ} = 25°C to T_{VJmax}	75	V
V_{GS}		±20	V
I_{D25}	T_C = 25°C	200	A
I_{D90}	T_C = 90°C	160	A
I_{F25}	(diode) T_C = 25°C	185	A
I_{F90}	(diode) T_C = 90°C	125	A

Symbol	Conditions	Characteristic Values (T_{VJ} = 25°C, unless otherwise specified) min.	typ.	max.	
R_{DSon}	V_{GS} = 10 V; I_D = 100 A		3.5	4.5	mΩ
V_{GSth}	V_{DS} = 20 V; I_D = 1 mA;	2		4	V
I_{DSS}	V_{DS} = 75 V; V_{GS} = 0 V; T_{VJ} = 25°C			1	µA
	T_{VJ} = 125°C		0.1		mA
I_{GSS}	V_{GS} = ±20 V; V_{DS} = 0 V			200	nA
Q_g	V_{GS}= 10 V; V_{DS} = 60 V; I_D = 25 A		220		nC
Q_{gs}			50		nC
Q_{gd}			75		nC
$t_{d(on)}$	V_{GS}= 10 V; V_{DS} = 30 V; I_D = 25 A; R_G = 10 Ω		670		ns
t_r			1020		ns
$t_{d(off)}$			1620		ns
t_f			1170		ns
V_F	(diode) I_F = 150 A; V_{GS} = 0 V		1.1	1.6	V
t_{rr}	(diode) I_F = 20 A; -di/dt = 100 A/µs; V_{DS} = 30 V		120		ns
R_{thJC}				0.55	K/W
R_{thJS}			tbd		K/W

Features

- trench MOSFET
  - very low on state resistance R_{DSon}
  - fast body diode
- DAB based ISOPLUS i4-PAC™ package
  - isolated back surface
  - low coupling capacity between pins and heatsink
  - enlarged creepage towards heatsink
  - application friendly pinout
  - low inductive current path
  - extremely high reliability
  - light weight
  - industry standard outline
  - UL registered E 72873

Applications

- automobiles and industrial vehicles
  - AC drives - starter generator for 42V etc.
  - choppers - replacing series resistors for DC drives, heating etc.
  - DC-DC converters - between 12V and 42V system etc.
  - electronic switches -replacing relays and fuses
- power supplies
  - DC-DC converters
  - solar inverters
  - converters for fuel cells
- battery supplied systems
  - choppers or inverters for drives in hand held tools
  - battery chargers

IXYS Semiconductor GmbH
Edisonstr. 15 D-68623 Lampertheim
IXYS Corporation
3540 Bassett Street, Santa Clara, CA 95054

Component

Symbol	Conditions	Maximum Ratings	
I_{RMS}	per pin	75	A
T_{VJ}		-55...+175	°C
T_{stg}		-55...+125	°C
V_{ISOL}	$I_{ISOL} \leq 1$ mA; 50/60 Hz	2500	V~
F_C	mounting force with clip	20...120	N

Symbol	Conditions	Characteristic Values min.	typ.	max.	
C_p	coupling capacity between shorted pins and mounting tab in the case		40		pF
d_S, d_A	pin - pin	1.7			mm
d_S, d_A	pin - backside metal	5.5			mm
Weight			5		g

Dimensions in mm (1 mm = 0.0394")